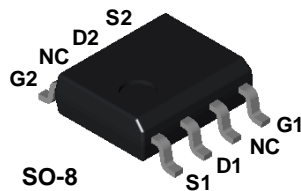


**NPDS402
NPDS403
NPDS404
NPDS406**



N-Channel General Purpose Dual Amplifier

Sourced from Process 98.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	50	V
V_{GS}	Gate-Source Voltage	50	V
I_{GF}	Forward Gate Current	10	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

General Purpose Dual Amplifier

(continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

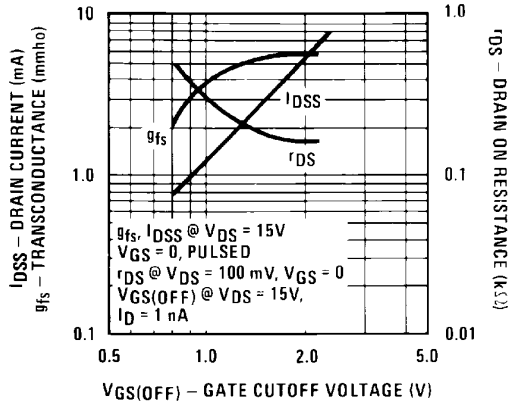
Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$	- 50		V
I_{GSS}	Gate Reverse Current	$V_{GS} = 30 V, V_{DS} = 0$		25	pA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = 15 V, I_D = 1.0 nA$	- 0.5	- 2.5	V
V_{GS}	Gate-Source Voltage	$V_{DG} = 15 V, I_D = 200 \mu A$		- 2.3	V
$V_{G1 - G2}$	Voltage Gate 1-Gate 2	$I_G = 1.0 \mu A, V_{DS} = 0$	+ / - 50		V
ON CHARACTERISTICS					
I_{DSS}	Zero-Gate Voltage Drain Current*	$V_{DS} = 10 V, V_{GS} = 0$	0.5	10	mA
SMALL SIGNAL CHARACTERISTICS					
g_{fs}	Common Source Forward Transconductance	$V_{DS} = 10 V, V_{GS} = 0, f = 1.0 kHz$ $V_{DS} = 15 V, I_D = 200 \mu A, f = 1.0 kHz$	2000 1000	7000 2000	$\mu mhos$ $\mu mhos$
g_{oss}	Common Source Output Conductance	$V_{DS} = 10 V, V_{GS} = 0, f = 1.0 kHz$		20	$\mu mhos$
g_{os}	Common Source Output Conductance	$V_{DS} = 15 V, I_D = 200 \mu A, f = 1.0 kHz$		2.0	$\mu mhos$
C_{iss}	Input Capacitance	$V_{DG} = 15 V, I_D = 200 \mu A,$ $f = 1.0 MHz$		8.0	pF
C_{rss}	Reverse Transfer Capacitance	$V_{DG} = 15 V, I_D = 200 \mu A,$ $f = 1.0 MHz$		3.0	pF
CMMR	Common Mode Rejection	$V_{DG} = 10 \text{ to } 20 V, I_D = 200 \mu A$	95		dB
$V_{GS1} - V_{GS2}$	Differential Match	$V_{DG} = 10 V, I_D = 200 \mu A,$ NPDS402 NPDS403 NPDS404 NPDS406		10 10 15 40	mV mV mV mV
$\Delta V_{GS1} - V_{GS2}$	Differential Drift	$V_{DG} = 10 V, I_D = 200 \mu A,$ $T_A = -55 \text{ to } 25^\circ C$ NPDS402 NPDS403 NPDS404 NPDS406 $V_{DG} = 10 V, I_D = 200 \mu A$ $T_A = 25 \text{ to } 125^\circ C$ NPDS402 NPDS403 NPDS404 NPDS406		10 25 25 80 10 25 25 80	$\mu V/^\circ C$ $\mu V/^\circ C$ $\mu V/^\circ C$ $\mu V/^\circ C$ $\mu V/^\circ C$ $\mu V/^\circ C$ $\mu V/^\circ C$ $\mu V/^\circ C$

*Pulse Test: Pulse Width ≤ 300 ms, Duty Cycle $\leq 2\%$

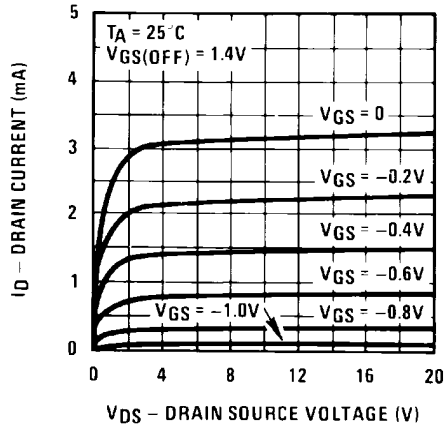
NPDS402 / NPDS403 / NPDS404 / NPDS406

Typical Characteristics (continued)

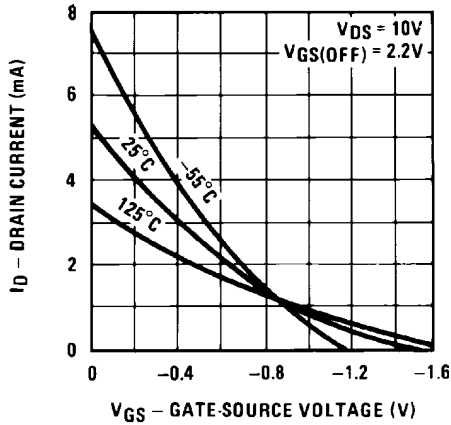
Parameter Interactions



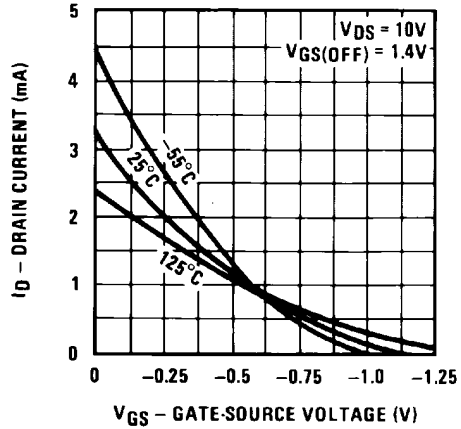
Common Drain-Source



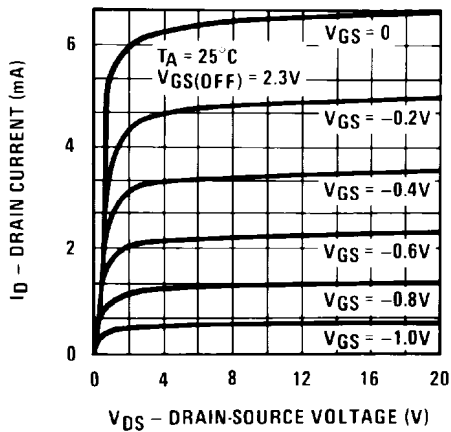
Transfer Characteristics



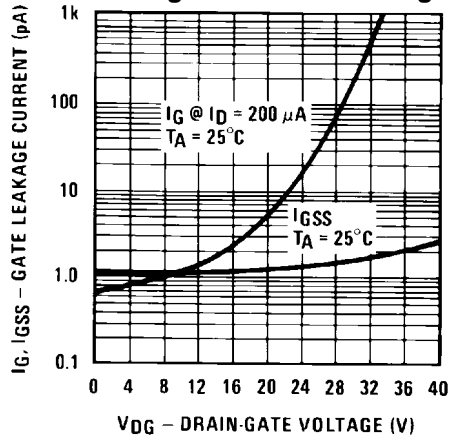
Transfer Characteristics



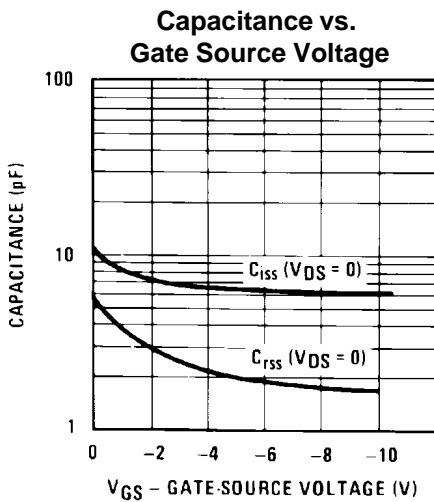
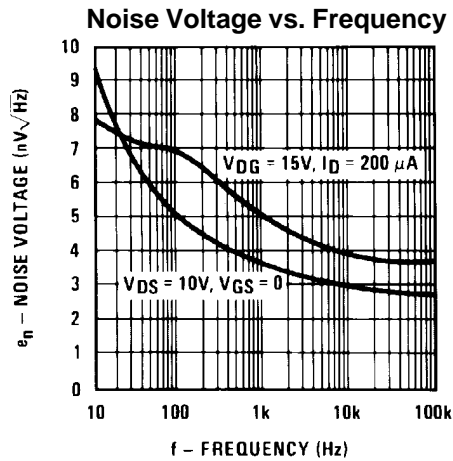
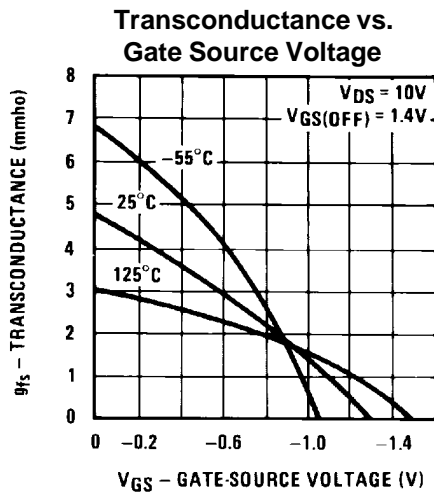
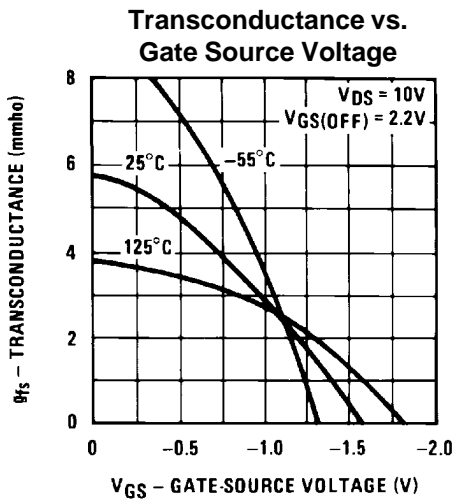
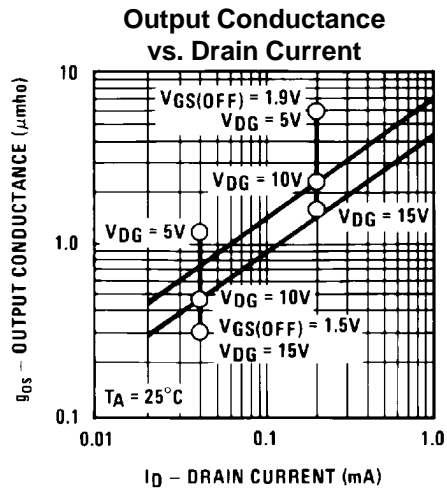
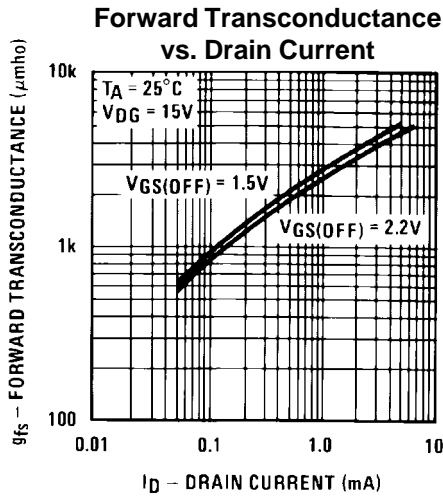
Common Drain Source



Gate Leakage Current vs. Voltage



Typical Characteristics (continued)



Typical Characteristics (continued)

